Extracting information from partially depleted Si detectors with digital sampling electronics

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- Studied Fazia telescope with 3 stages: SiI(300 μ m)-Si2(500 μ m)-CsI(10cm)
 - Current and charge signals digitized immediately after Preamplifier

• Sil full depleted (140V)

• Five different bias voltages applied on Si2 have been tested

| Vbias Si2 (∨) | Not Depleted depth (μm) | Depleted depth (µm) | Not Depleted depth (%) |
|---------------|-----------------------------------|-------------------------------|---------------------------|
| 105 | 200 | 310 | 40 |
| 130 | 170 | 340 | 30 |
| 200 | 90 | 420 | 20 |
| 235 | 50 | 460 | 10 |
| 290 | 0 | 510 | 0 |



- Only few % of difference observed between partially and totally depleted detector in efficiency of collection charge
- Energy resolution of ΔE-E matrix <u>does not change</u> even at 105V with 40% of detector thickness not depleted



PSA resolution change!!

A big difference in identification resolution has been observed between partially and totally depleted detector

much better isotopic separation is obtained using an underbiased detector